NSN 5961-00-890-9867

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-890-9867 **Inclosure Material:** Metal **Overall Length:** 0.188 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.220 inches **Internal Configuration:** Field effect **Electrode Internally-electrically Connected To Case:** Gate **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 15.0 drain to source voltage and 40.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 50.00 milliamperes gate current **Power Rating Per Characteristic:** 360.0 milliwatts total device dissipation **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No